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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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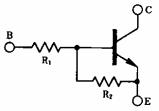


COMPOUND TRANSISTOR HD1 SERIES

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

- · High current drives such as IC outputs and actuators available
- On-chip bias resistor
- Low power consumption during drive



HD1 SERIES LISTS

Products	Marking	R1 (kΩ)	R₂ (kΩ)
HD1A3M	LP	1.0	1.0
HD1F3P	LQ	2.2	10
HD1L3N	LR	4.7	10
HD1A4M	LS	10	10
HD1L2Q	LT	0.47	4.7
HD1F2Q	LU	0.22	2.2
HD1A4A	LX	_	10

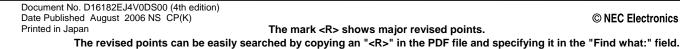
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	80	V
Collector to emitter voltage	VCEO	60	V
Emitter to base voltage	VEBO	10	V
Collector current (DC)	IC(DC)	1.0	А
Collector current (Pulse)	IC(pulse) Note1	2.0	А
Base current (DC)	IB(DC)	0.02	А
Total power dissipation	P⊤ ^{Note2}	2.0	W
Junction temperature	Tj	150	٥°
Storage temperature	Tstg	–55 to +150	°C

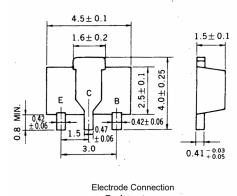
Notes 1. PW \leq 10 ms, duty cycle \leq 50 %

2. When 0.7 mm \times 16 cm² ceramic board is used

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PACKAGE DRAWING (UNIT: mm)



E. Emitter C. Collector

B. Base

HD1A3M
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	hfe1 Note	Vce = 2.0 V, Ic = 0.1 A	80			-
DC current gain	hFE2 Note	Vce = 2.0 V, Ic = 0.5 A	200			-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	VoL Note	V _{IN} = 5.0 V, Ic = 0.4 A			0.35	V
Low level input voltage	VIL Note	Vcε = 5.0 V, Ic = 100 μA			0.3	V
Input resistance	R1		0.7	1.0	1.3	kΩ
E-to-B resistance	R2		0.7	1.0	1.3	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1F3P

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = 60 V, I _E = 0			100	nA
DC current gain	hFE1 Note	Vce = 2.0 V, Ic = 0.1 A	200	630		-
DC current gain	hfe2 Note	Vce = 2.0 V, Ic = 0.5 A	300	780		-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200	430		-
Low level output voltage	VOL Note	$V_{IN} = 5.0 \text{ V}, \text{ Ic} = 0.3 \text{ A}$		0.12	0.3	V
Low level input voltage	VIL Note	Vcε = 5.0 V, lc = 100 μA		0.5	0.3	V
Input resistance	R1		1.54	2.2	2.86	kΩ
E-to-B resistance	R2		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1L3N

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hFE1 Note	Vce = 2.0 V, Ic = 0.1 A	200			_
DC current gain	hfe2 Note	Vce = 2.0 V, Ic = 0.5 A	300			_
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	VOL Note	V _{IN} = 5.0 V, Ic = 0.2 A			0.2	V
Low level input voltage	VIL Note	Vce = 5.0 V, Ic = 100 <i>µ</i> A			0.3	V
Input resistance	Rı		3.29	4.7	6.11	kΩ
E-to-B resistance	R2		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1A4M ELECTRICAL CHARAC	TERISTIC	CS (TA = 25°C)				
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 60 V, I_E = 0$			100	nA
DO 1	. Note					

Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, I_E = 0$			100	nA
DC current gain	hFE1 Note	Vce = 2.0 V, Ic = 0.1 A	200			-
DC current gain	hFE2 Note	$V_{CE} = 2.0 \text{ V}, \text{ Ic} = 0.5 \text{ A}$	300			-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	VOL Note	$V_{IN} = 5.0 \text{ V}, \text{ Ic} = 0.1 \text{ A}$			0.2	V
Low level input voltage	VIL Note	Vce = 5.0 V, Ic = 100 <i>µ</i> A			0.3	V
Input resistance	R1		7	10	13	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1L2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hFE1 Note	Vce = 2.0 V, lc = 0.1 A	200			-
DC current gain	hfe2 Note	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 Note	Vce = 2.0 V, lc = 1.0 A	200			-
Low level output voltage	VOL Note	$V_{IN} = 5.0 V$, Ic = 0.8 A			0.5	V
Low level input voltage	VIL Note	Vcε = 5.0 V, lc = 100 μA			0.3	V
Input resistance	R1		329	470	611	Ω
E-to-B resistance	R2		3.29	4.7	6.11	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1F2Q

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	hFE1 Note	Vce = 2.0 V, Ic = 0.1 A	100			-
DC current gain	hfe2 Note	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	VOL Note	$V_{IN} = 5.0 \text{ V}, \text{ Ic} = 0.8 \text{ A}$			0.5	V
Low level input voltage	VIL Note	Vcε = 5.0 V, lc = 100 μA			0.3	V
Input resistance	Rı		154	220	286	Ω
E-to-B resistance	R2		1.54	2.2	2.86	kΩ

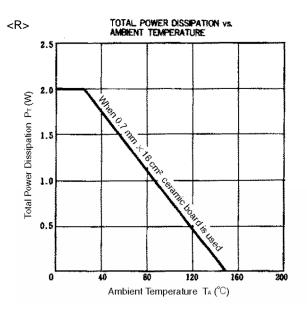
Note PW \leq 350 μ s, duty cycle \leq 2 %

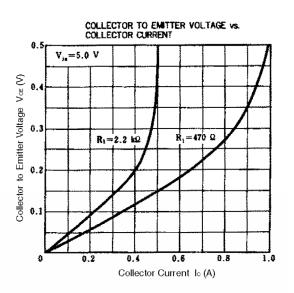
HD1A4A ELECTRICAL CHARACTERISTICS (T_A = 25°C)

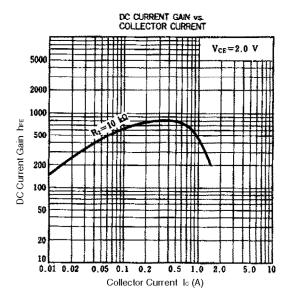
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hFE1 Note	$V_{CE} = 2.0 \text{ V}, \text{ Ic} = 0.1 \text{ A}$	200	630		-
DC current gain	hFE2 Note	Vce = 2.0 V, Ic = 0.5 A	300	780		-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200	430		-
Collector saturation voltage	$V_{\text{CE(sat)}} ^{\text{Note}}$	Ic = 0.7 A, I _B = 7 mA		0.25	0.4	V
Low level input voltage	VIL Note	Vcε = 5.0 V, lc = 100 μA		0.5	0.3	V
E-to-B resistance	R₂		7	10	13	kΩ

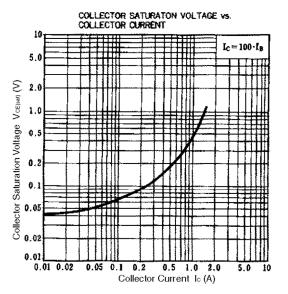
Note PW \leq 350 μ s, duty cycle \leq 2 %

TYPICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$









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